

(1) ADG: Automotive and Discrete Group

PCN Product/Process Change Notification					
	Mold compo	und re	placement for TO92		
Notification number:	ADG-DIS/19/xxxx		Issue Date	05/04/2019	
Issued by	Aline Augis				
Product series affected by the change			SCR Thyristor X006, X00619 and X02 series in TO92 Triac Z01 and Z00607 series in TO92 ST THYRISTOR ASD in TO92 ACS SERIES in TO92		
Type of change			Back end realization		
Description of the change Mold compound replaceme	ent for the Thyristors	housed	in TO92 package.		
Reason for change					
Product discontinuance from	m the current supplie	ər.			
Former versus changed p	product:	The cha dimens current	nanged products do not present modified electrical, sional or thermal parameters, leaving unchanged the t information published in the product datasheet		
		The foo	ptprint recommended by ST	remains the same.	
		There is delivery	s no change in the packing / quantities either.	modes and the standard	
		The pro ECOPA	oducts remain in full complia ACK®2 grade ("halogen-free	ince with the ST e").	
Disposition of former pro	ducts				
Delivery of former products will be done until stock depletion.					
Marking and traceability					
The traceability is ensured by the internal codification and the QA number.					
No change of marking. A specific letter (N) adding at the end of the finished good name:With previous compound= X00602MA1AA2\EWith new compound= X00602MA1AA2\EN					
Qualification complete da	ite		April 2019		

STMicroelectronics ADG¹ – Discrete and Filter Division BU Thyristors and AC Switches



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Product family	Sub-family	Commercial part Number	Availability date
TRIAC	TO92	ACS108-6SA-TR Week-18	
TRIAC	TO92	ACS108-8SA-TR	Week-20
THYRISTOR	TO92	P0102DA 5AL3	Week-20
THYRISTOR	TO92	P0130AA 2AL3	Week-20
THYRISTOR	TO92	TS110-7A1	Week-20
THYRISTOR	TO92	TS110-8SA1	Week-18
THYRISTOR	TO92	X00602MA 5AL2	Week-18
THYRISTOR	TO92	X00619MA5AL2	Week-18
THYRISTOR	TO92	X0202MA 2BL2	Week-20
THYRISTOR	TO92	X0205MA 2BL2	Week-20
TRIAC	TO92	Z00607MA 1BA2	Week-18
TRIAC	TO92	Z0103MA 2AL2	Week-20
TRIAC	TO92	Z0103NA 2AL2	Week-20
TRIAC	TO92	Z0107MA 2AL2	Week-20
TRIAC	TO92	Z0107NA 2AL2	Week-20
r commercial part number <s after="" entry.<br="" order="">nge implementation sch</s>	s can be made availab	le on demand, the typica	I lead time for availability is
Sales types	Estimated p	production start	Estimated first shipmen
All CP	Week	27-2019	Week 29-2019
nments:			
tomor's foodback		1	

Absence of acknowledgement of this PCN within 30 days of receipt will constitute acceptance of the change Absence of additional response within 90 days of receipt of this PCN will constitute acceptance of the change

Qualification	program an	d results
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QRP19032 Attached



External Reliability Evaluation Report

New Resin Qualification on TO-92 package

Genera	Information	Loca	tions
Product Lines	BU 58	Wafer fab	STMicroelectronics Tours (FRANCE)
Products Description	TS110x XL0840x ACS10x P01x	Assembly plant	Subcontractor 994X (CHINA)
	X0x Z0x FLC21-135A	Reliability Lab	STMicroelectronics Tours (FRANCE)
Product Group	ADG	Reliability assessment	Pass
Product division	Discrete & Filter Division		
Package	TO-92		
Maturity Step Level	Qualified		

DOCUMENT INFORMATION

Version	Date	Pages	Prepared by	Approved by	Comment
Rev. 1	March 26 th ; 2019	11	Erika LAURET	Julien MICHELON	First issue

Note: This report is a summary of the reliability trials performed in good faith by STMicroelectronics in order to evaluate the potential reliability risks during the product life using a set of defined test methods.

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1 APPLICABLE AND REFERENCE DOCUMENTS

Document reference	Short description		
JESD 22	Reliability test methods for packaged devices		
JESD 47	Stress-Test-Driven Qualification of Integrated Circuits		
JESD 94	Application specific qualification using knowledge based test methodology		
MIL-STD-750C	Test method for semiconductor devices		

2 GLOSSARY

ВОМ	Bill Of Materials
DUT	Device Under Test
HTRB	High Temperature Reverse Bias
тс	Temperature Cycling
ТНВ	Temperature Humidity Bias
RSH	Resistance to Solder Heat
UHAST	Unbiased Highly Accelerated Stress Test
P/N	Part Number
RH	Relative Humidity
SS	Sample Size



3 RELIABILITY EVALUATION OVERVIEW

3.1 **Objectives**

Qualification of new resin assembled in TO-92 package.

3.2 Conclusion

Qualification plan has been fulfilled without exception. Reliability tests have shown that those devices behave correctly against environmental tests (no failure). Moreover, the stability of electrical parameters during the accelerated tests demonstrates the robustness of those products and safe operation, which is consequently expected during their lifetime.



4 CHANGE DESCRIPTION

Qualification of new supplier of Halogen-Free Molding Compound for TO-92 package at subcontractor in China in replacement of current resin.

5 TESTS RESULTS SUMMARY

5.1 <u>Test vehicles</u>

Four test vehicles were chosen:

- ACS108-8TK-TR
- Z00607MA 1BA2
- P0102DA 5AL3
- TS110-8SA1

Lot #	Part number	Package	Comment
Lot 1	ACS108-8TK-TR	TO-92	Qualification data
Lot 2	Z00607MA 1BA2	TO-92	Qualification data
Lot 3	P0102DA 5AL3	TO-92	Qualification data
Lot 4	TS110-8SA1	TO-92	Qualification data



5.2 Test plan and results summary

Teet	Tast Std raf Canditions SS		SS Stop	Failure/SS				
Test	Sta fei.	Conditions	22	Step	Lot 1	Lot 2	Lot 3	Lot 4
		Die Oriente	ed Te	sts				
HTRB	JESD22 A-108 MIL-STD-750C	Temperature=125°C Tension= VAC 600V	77	1000h		0/77		
HTRB	JESD22 A-108 MIL-STD-750C	Temperature=125°C Tension= VAC 800V	154	1000h	0/77			0/77
		Package Orie	ented	Tests				
тс	JESD22 A-104	Frequency (cy/h)=2cy/h Temperature (high)=150°C Temperature (low)=-65°C	308	500cy	0/77	0/77	0/77	0/77
RSH	ST 0060102 JESD22 B-106-A	Temperature=260°C Time (on)=10s	30	MESURE AFTER DIP			0/30	
ТНВ	JESD22 A-101	Humidity (HR)=85% Temperature=85°C Tension=100V	74	1000h	0/25	0/25		0/24*
UHAST	JESD22 A-118	Humidity (HR)=85% Pressure=2.3bar Temperature=130°C	231	96h	0/77	0/77		0/77

* Note: quantity reduced due to scrap unit



6 ANNEXES

6.1 <u>Device details</u>

6.1.1 Pin connection

Refer to products datasheets.

6.1.2 Package outline/Mechanical data

Refer to products datasheets



6.2 <u>Tests Description</u>

Test name	Standard Reference	Description	Purpose		
	Die Oriented				
HTRB High Temperature Reverse Bias	JESD22 A- 108 MIL-STD- 750C	HTRB : High Temperature Reverse Bias HTFB / HTGB : High Temperature Forward (Gate) Bias. The device is stressed in static configuration, trying to satisfy as much as possible the following conditions: - low power dissipation; - max. supply voltage compatible with diffusion process and internal circuitry limitations.	To determine the effects of bias conditions and temperature on solid state devices over time. It simulates the devices' operating condition in an accelerated way. To maximize the electrical field across either reverse biased junctions or dielectric layers, in order to investigate the failure modes linked to mobile contamination, oxide ageing, layout sensitivity to surface effects.		
		Package Oriented			
TC Temperature Cycling	JESD22 A- 104	The device is submitted to cycled temperature excursions, between a hot and a cold chamber in air atmosphere.	To investigate failure modes related to the thermo-mechanical stress induced by the different thermal expansion of the materials interacting in the die-package system. Typical failure modes are linked to metal displacement, dielectric cracking, molding compound delamination, wire bonds failure, die-attach layer degradation.		
THB Temperature Humidity Bias	JESD22 A- 101	The device is biased in static configuration minimizing its internal power dissipation, and stored at controlled conditions of ambient temperature and relative humidity.	To evaluate the package moisture resistance with electrical field applied, both electrolytic and galvanic corrosion are put in evidence.		
RSH Resistance to solder heat	ST 0060102 JESD22 B- 106-A	Device is submitted to a dipping in a solder bath at 260°C with a dwell time of 10s. Only for through hole mounted devices.	This test is used to determine whether solid state devices can withstand the effects of the temperature to which they will be subjected during soldering of their leads. The heat is conducted through the leads into the device package from solder heat at the reverse side of the board. This procedure does not simulate wave soldering or reflow heat exposure on the same side of the board as the package body.		
UHAST Unbiased Highly Accelerated Stress Test	JESD22 A- 118	The device is stored in saturated steam, at fixed and controlled conditions of pressure and temperature.	To investigate corrosion phenomena affecting die or package materials, related to chemical contamination and package hermeticity.		



6.3 List of product involved in this qualification

X00602MA 1AA2	P0102DA 5AL3
X00602MA 2AL2	P0109DA 5AL3
X00602MA 5AL2	P0111DA 1AA3
X00619MA1AA2	P0111DA 5AL3
X00619MA2AL2	P0111MA 1AA3
X00619MA5AL2	P0111MA 1AA3
X0202DA 1BA2	P0111MA 1AA3
X0202MA 1BA2	P0115DA 5AL3
X0202MA 2BL2	P0115DA 5AL3
X0202NA 1BA2	P0118DA 1AA3
X0202NA2BL2	P0118DA 1AA3
X0203MA 1BA2	P0118MA 2AL3
X0203NA 1BA2	P0118MA 5AL3
X0205MA 1BA2	P0124CA 5AL3
X0205MA 2BL2	P0130AA 1EA3
X0205NA 1BA2	P0130AA 2AL3
X0225MA 1DA2	ACS102-6TA-TR
X0227MA 5DL2	FLC21-135A
Z00607MA 1BA2	XL0840
Z00607MA 2BL2	XL0840-AP
Z00607MA 5BL2	XL0840-TR
Z0103MA 1AA2	ACS108-6SA
Z0103MA 2AL2	ACS108-6SA-AP
Z0103MA 5AL2	ACS108-6SA-TR
Z0103NA 1AA2	ACS108-8SA
Z0103NA 2AL2	ACS108-8SA-AP
Z0107DA 2AL2	ACS108-8SA-TR
Z0107MA 1AA2	TS110-7A1
Z0107MA 2AL2	TS110-7A1-AP
Z0107MA 5AL2	TS110-8A1
Z0107NA 1AA2	TS110-8A1-AP
Z0107NA 2AL2	TS110-8A2
Z0107NA 5AL2	TS110-8A2-AP
Z0109MA 1AA2	TS110-8SA1
Z0109MA 2AL2	TS110-8SA1-AP
Z0109MA 5AL2	TS110-8SA2
Z0109NA 2AL2	TS110-8SA2-AP
Z0110MA 1AA2	
Z0127MA 2EL2	
P0102DA 1AA3	
P0102DA 2AL3	